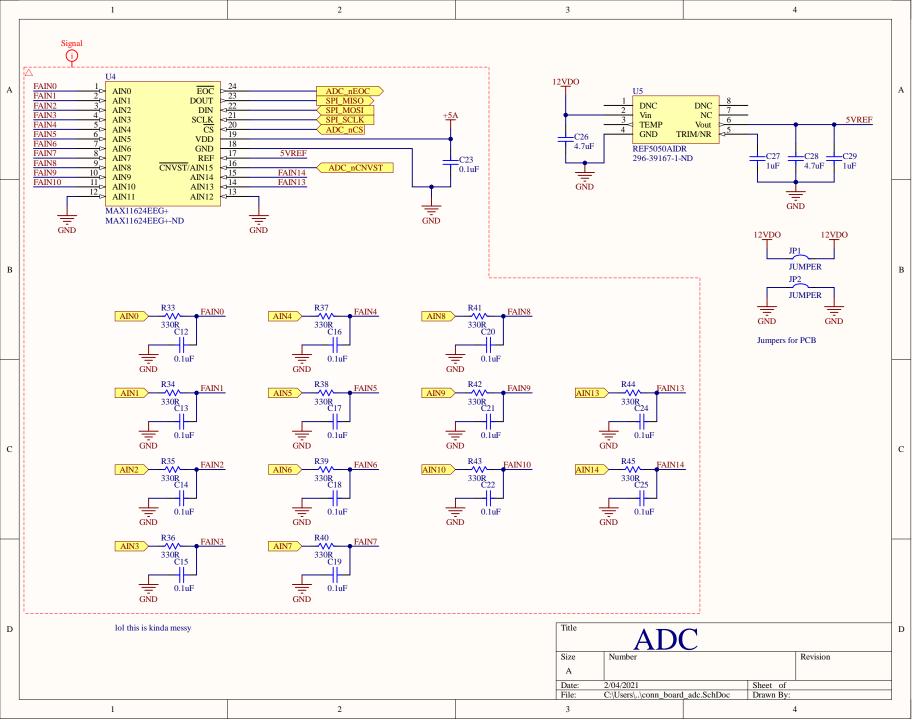
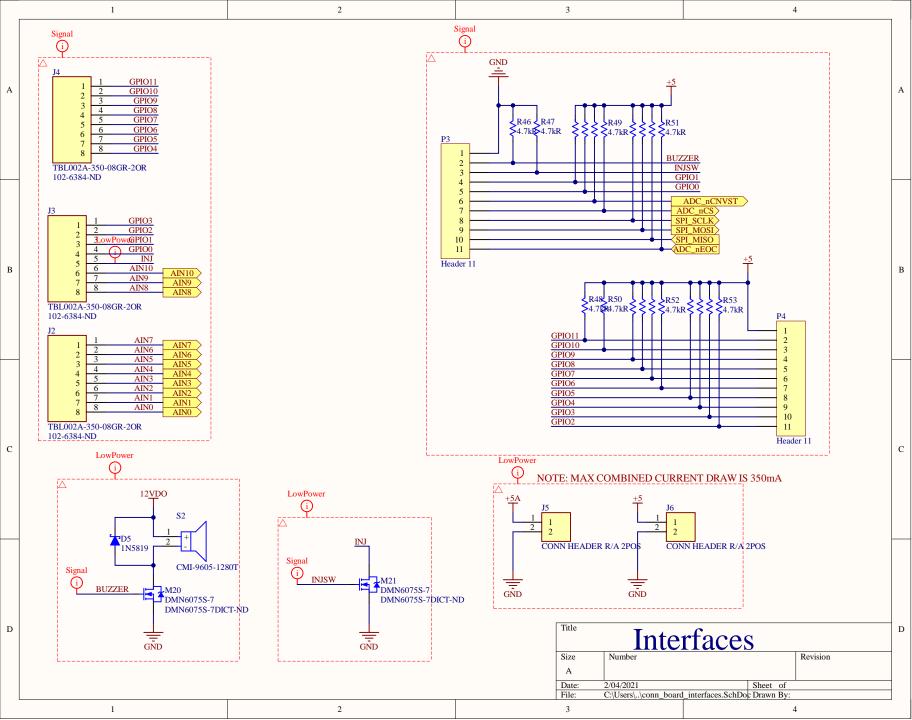
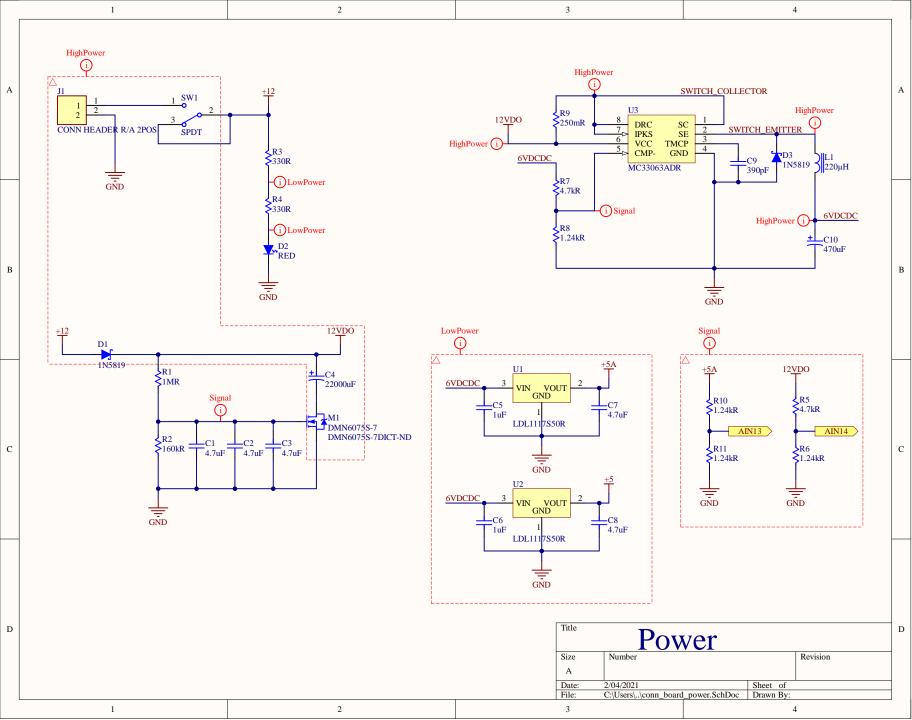
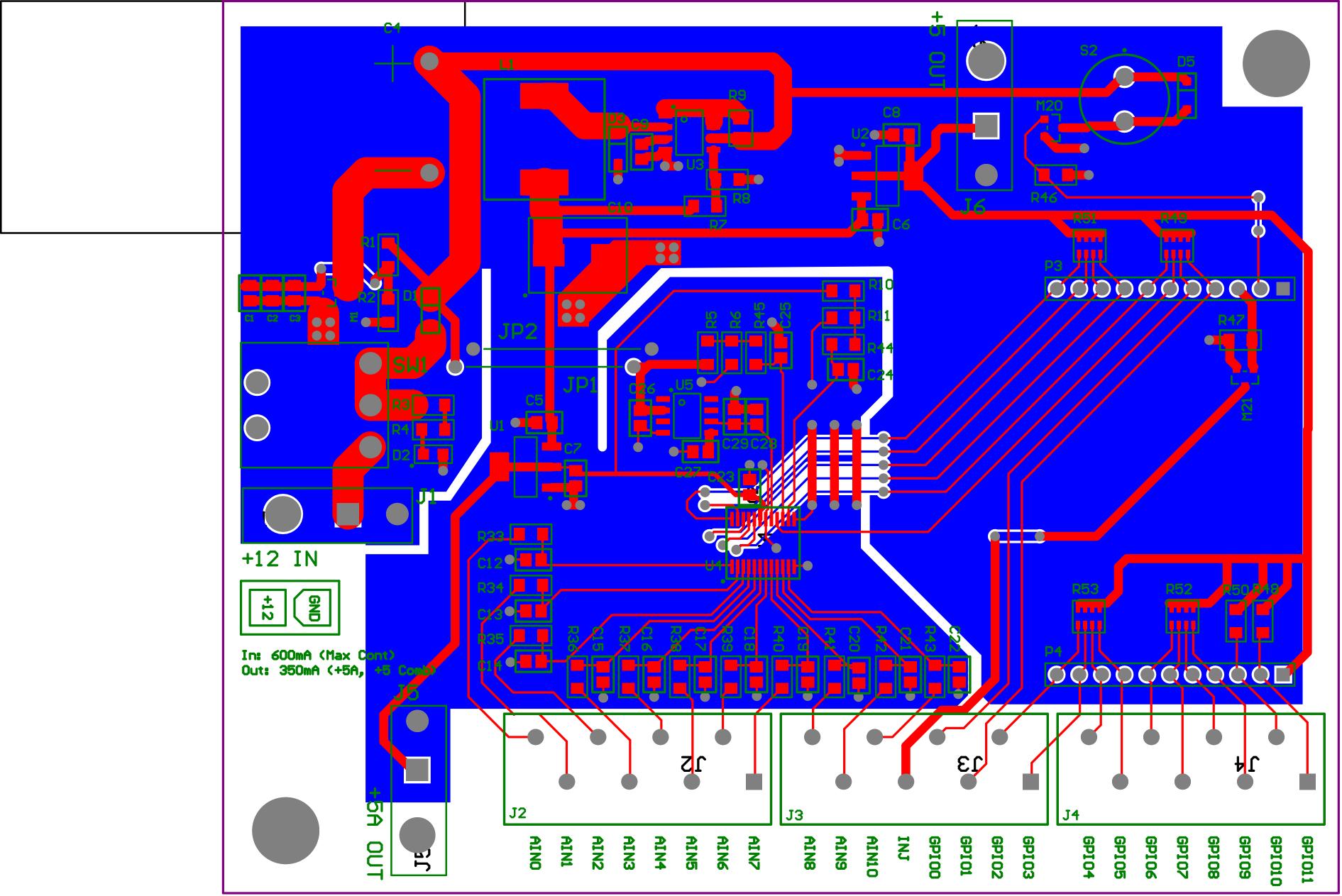
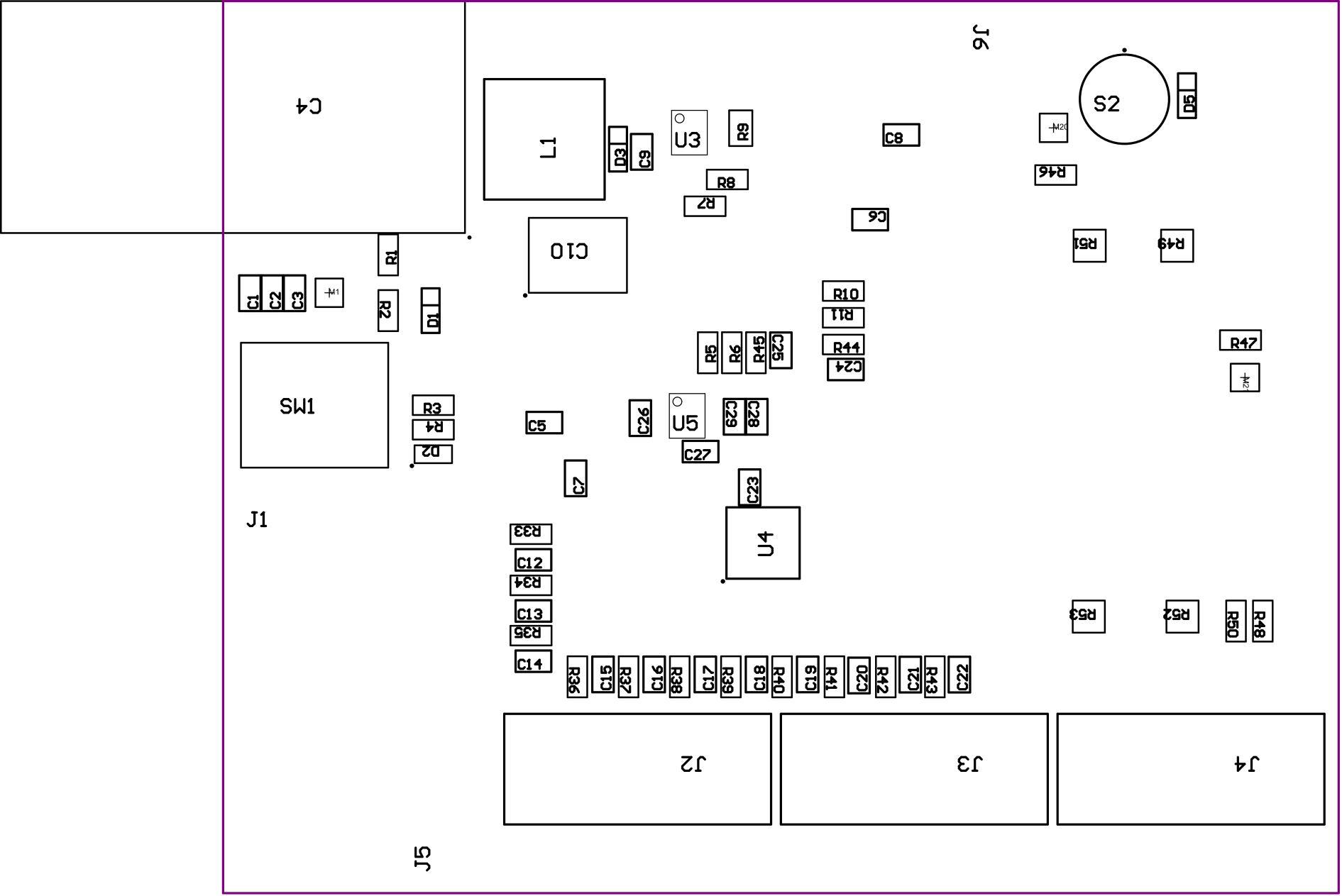
MAJABURA I FERRO APPROVED AND A COLOR OF STREET AND A COLOR OF S	Line #	Name	Description	Designator Quantity	Manufacturer 1	Manufacturer Part Number 1	Manufacturer Lifecycle 1	Supplier 1	Supplier Part Number 1	Supplier Unit Price 1	Supplier Subtotal 1
A		4.7uF	SMD Multilayer Ceramic Capacitor, 4.7 µF, 25 V, 0805		7 Samsung	CL21A475KAQNNNE	Volume Production	Digi-Key	1276-1244-1-ND	0.11	0.77
19 19 19 19 19 19 19 19		22000uF		C4	1 Nichicon	UVR1C223MRD6	Volume Production	Digi-Key	493-1054-ND	4.11	4.11
Sept		1uF	·		4 KEMET	C0805C105Z4VACTU	Volume Production	Digi-Key	399-8011-1-ND	0.11	0.44
OLD 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100 100		390pF	Cap Ceramic 390pF 50V COG 5% SMD 0805 125C Paper		1 Samsung	CL21C391JBANNNC	Volume Production	Digi-Key	1276-1303-1-ND	0.11	0.11
Date Color For a TUE POWER REDS		470uF		C10	1 Nichicon	UUD1C471MNL1GS	Volume Production	Digi-Key	493-2266-1-ND	0.82	0.82
BRD MAX S00712 MAX S00712		0.1uF	CAP CER 0.1UF 25V X7R 0805	C15, C16, C17, C18, C19, C20, C21, C22, C23,	4 KEMET	C0805C104M3RACTU	Volume Production	Digi-Key	399-8000-1-ND	0.062	0.868
Sept December De		1N5819		D1, D3, D5	3 Diodes	1N5819HW-7-F	Volume Production	Digi-Key	1N5819HW-FDICT-ND	0.43	1.29
READER COMN HEADER RVA 28/DS 11.55 Molec 1724480002 Not Recommendation Opj-Key VAN16/206-ND 0.55 1.65		RED	WURTH ELEKTRONIK 150080SS75000 LED, 0805, SUP	D2	1 Wurth Electronics	150080\$\$75000	Volume Production	Digi-Key	732-4985-1-ND	0.18	0.18
FEBODA 1-24 Poles, Screwies, 45A*, 3.50 Pitch, 24-20 (AWG) 27, 13, 44 3 CUI Devices TBI 002A 356 GBGR 20R Unknown Digi-Key 102-6384 NID 1.28 3.84		HEADER	CONN HEADER R/A 2POS	J1, J5, J6	3 Molex	1724480002		Digi-Key	WM16206-ND	0.55	1.65
BOURNS SRR1260-221K NOUTOR, SHELDED, 1 Bourns SRR1260-221K Volume Production Digk-Key SRR1260-221KT-ND 1.19 1.19		TBL002A- 350- 08GR-		J2, J3, J4	3 CUI Devices	TBL002A-350-08GR-2OR	Unknown	Digi-Key	102-6384-ND	1.28	3.84
20UH 1.34, SMD MOSET 60V N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60V N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60V N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60V N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60V N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60V N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60V N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60V N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60V N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60V N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60V N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60V N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60V N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60V N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60V N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60V N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60V N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60V N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60V N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60V N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60V N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60V N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60V N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60V N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60V N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60V N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60Vg N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60Vg N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60Vg N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60Vg N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60Vg N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60Vg N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60Vg N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60Vg N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60Vg N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60Vg N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60Vg N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60Vg N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60Vg N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60Vg N: Ch Enh FET 20Vgs 0.8W 600pf MI, M20, MST 60Vg			ROLIBNS SPR1260-221K INDUCTOR SHIFLDED	JP1, JP2	2						
SS-7 MUDEL 1-00 / PLD EMPT 100 / PLD EMPT 100 / PLD 100					1 Bourns	SRR1260-221K	Volume Production	Digi-Key	SRR1260-221KCT-ND	1.19	1.19
11 11 11 11 12 12 13 14 15 15 15 16 16 16 16 16		5S-7	MOSFET 60V N-Ch Enh FET 20Vgss 0.8W 600pF		3 Diodes	DMN6075S-7	Volume Production	Digi-Key	DMN6075S-7DICT-ND	0.35	1.05
Moded SMD Punched Carrier T/R R1				P3, P4	2						
16MR Molded SMD Punched Carrier T/R 12 Panasonic ER-6EN1-16G3V Volume Production Uijk-Key P100KCL1-ND U.1		1MR	· · ·	R1	1 Panasonic	ERJ-6ENF1004V	Volume Production	Digi-Key	P1.00MCCT-ND	0.1	0.1
Res Thin Film 0805 330 Ohm 0.5% 0.125W(1/8W) R37, R38, R39, R40, R41, R42, R43, R44, R45 R5 Panasonic ERA-6AED331V Volume Production Digi-Key P123837CT-ND 0.094 1.41		160kR	· ·	R2	1 Panasonic	ERJ-6ENF1603V	Volume Production	Digi-Key	P160KCCT-ND	0.1	0.1
4.//KR		330R		R34, R35, R36, R37, R38, R39, R40, R41, R42,	5 Panasonic	ERA-6AED331V	Volume Production	Digi-Key	P123837CT-ND	0.094	1.41
1.24RK RES SMD 1,24K OHM 0,5% 1/4W 0805 R11 4 Panasonic ERJ-PBD 124 IV New Product Digi-Key P21029CI-ND 0.23 0.92		4.7kR	` '		6 Panasonic	ERA-6AED472V	Volume Production	Digi-Key	P123914CT-ND	0.1	0.6
250mR Res Thick Film 1206 250m Ohm 1% 1/2W 100ppm/C R9		1.24kR	RES SMD 1.24K OHM 0.5% 1/4W 0805		4 Panasonic	ERJ-PB6D1241V	New Product	Digi-Key	P21029CT-ND	0.23	0.92
4.7kR RES ARRAY 4 RES 4.7K OHM 1206 R49, R51, R52, R53 4 Bourns CAY16-472J4LF Volume Production Digi-Key CAY16-472J4LFCT-ND 0.1 0.4 CMI-9605-1280T Unknown Digi-Key 102-CMI-9605-1280T-ND 1.22 1.22 SPDT Switch Toggle ON None ON SPDT Round Lever PC Pins 5A 250VAC 28VDC PC Mount with Bracket SA 250VAC 28VDC PC Mount with Bracket Unknown Digi-Key SOIC -40 to 85 Unknown MAX11624EEG+ Volume Production Digi-Key MAX11624EEG+ND 5.57 5.57 Unknown SOIC -40 to 85 Unknown SOIC -40 to 85 Unknown MAX11624EEG+ Volume Production Digi-Key MAX11624EEG+ND 5.57 5.57 5.57 Unknown Reposition Digi-Key SOIC -40 to 85 Unknown SOIC -40 to 85 Unknown MAX11624EEG+ Volume Production Digi-Key MAX11624EEG+ND 5.57 5.57 5.57 Unknown SOIC -40 to 85 Unknown SOIC -40 to 85 Unknown MAX11624EEG+ Volume Production Digi-Key MAX11624EEG+ND 5.57 5.57 5.57 5.57 5.57 5.57 5.57 5.5		250mR	· ·		11 '	CSR1206FKR250	Volume Production	Digi-Key	CSR1206FKR250CT-ND	0.4	0.4
9605- 1280T 2.7kHz 80dB @ 12V, 10cm Through Hole PC Pins 52 1 CUI CMI-9605-1280T Unknown Digi-Key 102-CMI-9605-1280T-ND 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.22 1.		4.7kR	·			CAY16-472J4LF	Volume Production	Digi-Key	CAY16-472J4LFCT-ND	0.1	0.4
SPDT Switch Toggle ON None ON SPDT Round Lever PC Pins 5A 250VAC 28VDC PC Mount with Bracket SW1 1 E-Switch 100SP1T2B4M6QE Volume Production Digi-Key EG2362-ND 2.67 2.67 LDL1117S LDL1117 Series 1.2 A 5 V High PSRR LDO Linear Voltage Regulator - SOT-223 U1, U2 2 STMicroelectronic STMICROELECTRONIC STATE CONTROLL LDL1117S50R Unknown Digi-Key 497-17240-1-ND 0.57 1.14 MC33063 1.5-A peak boost/buck/inverting switching regulator 8-ADR SOIC -40 to 85 U3 1 Texas Instruments MC33063ADR Volume Production Digi-Key 296-17763-1-ND 0.46 0.46 MAX1162 4EEG+ 4EG+ GLOVE, POLYAMIDE, L/FREE, PU, SIZE 6 - More Details 4EG+ U4 1 Maxim MAX11624EEG+ Volume Production Digi-Key MAX11624EEG+-ND 5.57 5.57 REF5050 TEXAS INSTRUMENTS - REF5050AIDR - VOLTAGE REF, REF5050AIDR - VOLTAGE REF, LIS 1 Texas Instruments REF5050AIDR - Volume Production Digi-Key 296-30167-1-ND 3.00 3.00		9605-			1 CUI	CMI-9605-1280T	Unknown	Digi-Key	102-CMI-9605-1280T-ND	1.22	1.22
LDL1117S LDL1117 Series 1.2 A 5 V High PSRR LDO Linear Voltage V1, U2 2 STMicroelectronic STMicroelectronic LDL1117S50R Unknown Digi-Key 497-17240-1-ND 0.57 1.14				SW1	1 E-Switch	100SP1T2B4M6QE	Volume Production	Digi-Key	EG2362-ND	2.67	2.67
MC33063 1.5-A peak boost/buck/inverting switching regulator 8- ADR SOIC -40 to 85 U3 1 Texas Instruments MC33063ADR Volume Production Digi-Key 296-17763-1-ND 0.46 0.46 MAX1162 4EEG+ GLOVE, POLYAMIDE, L/FREE, PU, SIZE 6 - More Details U4 1 Maxim MAX11624EEG+ Volume Production Digi-Key MAX11624EEG+-ND 5.57 5.57 REF5050 TEXAS INSTRUMENTS - REF5050AIDR - VOLTAGE REF, U5 1 Texas Instruments REF5050AIDR - Volume Production Digi-Key 296-30167-1-ND 3.09 3.09			LDL1117 Series 1.2 A 5 V High PSRR LDO Linear Voltage	U1, U2	2 STMicroelectronic	LDL1117S50R	Unknown	Digi-Key	497-17240-1-ND	0.57	1.14
MAX1162 4EEG+ GLOVE, POLYAMIDE, L/FREE, PU, SIZE 6 - More Details U4 1 Maxim MAX11624EEG+ Volume Production Digi-Key MAX11624EEG+-ND 5.57 5.57 REF5050 TEXAS INSTRUMENTS - REF5050AIDR - VOLTAGE REF, U5 1 Texas Instruments REF5050AIDR Volume Production Digi-Key 296.30167.1.ND 3.09 3.09				U3	1 Texas Instruments	MC33063ADR	Volume Production	Digi-Key	296-17763-1-ND	0.46	0.46
REF5050 TEXAS INSTRUMENTS - REF5050AIDR - VOLTAGE REF, II5 1 Toyas Instruments DEF5050AIDR Volume Production Digitary 296-30167-1-ND 3.00 3.00		MAX1162		U4	1 Maxim	MAX11624EEG+	Volume Production	Digi-Key	MAX11624EEG+-ND	5.57	5.57
		REF5050		U5	1 Texas Instruments	REF5050AIDR	Volume Production	Digi-Key	296-39167-1-ND	3.09	3.09











Design Rules Verification Report

Filename: C:\Users\Public\Documents\Altium\Projects\EFIPCB_2020\conn_board\conn_board

Warnings 0 Rule Violations 5

Warnings	
Total	0

Rule Violations	
Clearance Constraint (Gap=0.254mm) (All),(All)	0
Clearance Constraint (Gap=0.254mm) (All),(All)	0
Short-Circuit Constraint (Allowed=No) (All),(All)	0
Un-Routed Net Constraint ((All))	0
Modified Polygon (Allow modified: No), (Allow shelved: No)	0
Width Constraint (Min=0.254mm) (Max=2mm) (Preferred=1.5mm) (InNetClass('LowPower'))	0
Width Constraint (Min=0.127mm) (Max=1mm) (Preferred=0.254mm) (InNetClass('Signal'))	0
Width Constraint (Min=0.127mm) (Max=1mm) (Preferred=0.254mm) (All)	0
Width Constraint (Min=1mm) (Max=5.5mm) (Preferred=3.3mm) (InNetClass('HighPower'))	0
Width Constraint (Min=0.127mm) (Max=5.5mm) (Preferred=0.254mm) (InNet('GND'))	0
Width Constraint (Min=0.254mm) (Max=0.254mm) (Preferred=0.254mm) (All)	0
Power Plane Connect Rule(Relief Connect)(Expansion=0.508mm) (Conductor Width=0.254mm) (Air Gap=0.254mm)	0
Minimum Annular Ring (Minimum=0.15mm) (All)	0
Minimum Annular Ring (Minimum=0.23mm) (IsVia)	0
Hole Size Constraint (Min=0.25mm) (Max=6.3mm) (All)	0
Hole Size Constraint (Min=0.3mm) (Max=6.3mm) (IsVia)	0
Hole Size Constraint (Min=0.025mm) (Max=2.54mm) (All)	0
Hole Size Constraint (Min=0.7mm) (Max=6.35mm) (IsPad)	0
Hole To Hole Clearance (Gap=0.254mm) (All),(All)	0
Hole To Hole Clearance (Gap=0.5mm) (All),(All)	5
Silk To Solder Mask (Clearance=0.15mm) (IsPad),(All)	0
Silk to Silk (Clearance=0.254mm) (All),(All)	0
Net Antennae (Tolerance=0mm) (All)	0
Board Clearance Constraint (Gap=0mm) (All)	0
Height Constraint (Min=0mm) (Max=25.4mm) (Prefered=12.7mm) (All)	0
Total	5

Hole To Hole Clearance (Gap=0.5mm) (All),(All)

Hole To Hole Clearance Constraint: (Collision < 0.5mm) Between Pad SW1-1(16.5mm,50mm) on Multi-Layer And Pad SW1-1(16.5mm,50mm) on Hole To Hole Clearance Constraint: (Collision < 0.5mm) Between Pad SW1-2(16.5mm,54.7mm) on Multi-Layer And Pad SW1-2(16.5mm,54.7mm) on Hole To Hole Clearance Constraint: (Collision < 0.5mm) Between Pad SW1-3(16.5mm,59.4mm) on Multi-Layer And Pad SW1-3(16.5mm,59.4mm) on Hole To Hole Clearance Constraint: (Collision < 0.5mm) Between Pad SW1-4(3.8mm,52.16mm) on Multi-Layer And Pad SW1-4(3.8mm,52.16mm) on Hole To Hole Clearance Constraint: (Collision < 0.5mm) Between Pad SW1-4(3.8mm,57.24mm) on Multi-Layer And Pad SW1-4(3.8mm,57.24mm) on Multi-Layer